APPLICATION DATA SHEET

Electronic Version v14

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Title of Invention

[LOW TEMPERATURE POLYSILICON THIN FILM TRANSISTOR AND METHOD OF MANUFACTURING THE SAME]

Application Type : regular, utility
Attorney Docket Number : 10958-US-PA

Correspondence address:

Customer Number: 31561

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Inventors Information:

Inventor 1:

Applicant Authority Type: Inventor Citizenship: TW
Name prefix: Mr.

Given Name: Chia-Tien Family Name: Peng

Residence:

City of Residence: Hsinchu Hsien

Country of Residence: TW

Address-1 of Mailing Address: No. 10, Alley 9, Lane 239, Paiti St., Chupei City

Address-2 of Mailing Address:

City of Mailing Address: Hsinchu Hsien

State of Mailing Address:

Postal Code of Mailing Address:

Country of Mailing Address: TW

Phone: Fax:

E-mail:

Inventor 2:

Applicant Authority Type: Inventor

Citizenship: TW

Name prefix: Mr.

Given Name: Ming-Wei

Family Name: Sun

Residence:

City of Residence: Kaohsiung

Country of Residence: TW

Address-1 of Mailing Address: 9Fl.-3, No. 342, Chungde Rd., Tzuoying Chiu

Address-2 of Mailing Address:

City of Mailing Address: Kaohsiung

State of Mailing Address:

Postal Code of Mailing Address: 813
Country of Mailing Address: TW

Phone: Fax:

E-mail:

Attorney Information:

practitioner(s) at Customer Number:

31561



as our attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.